AMENDMENT

Please amend the claims as follows:

- (amended herein) A <u>treatment</u> system for the treatment of effluent gases from a semiconductor device manufacturing process, the <u>treatment</u> system comprising:
 - (a) an abatement system comprising:
 - i) a burn/wet scrubber for receiving a flow of effluent gas containing a toxic constituent and for producing a flow of treated gas and a flow of waste[[-]]water containing the toxic constituent; and
 - ii) a localized wastewater treatment unit comprising an ion exchange filter selected to reduce the concentration of said toxic constituent, for receiving said flow of wastewater containing the toxic constituent, [[
- (b) a local waste water treatment unit associated with the burn/wet scrubber for receiving the flow of wastewater containing the toxic constituent]] and for producing a flow of locally treated wastewater from which the toxic constituent has been abated.
- 2. (amended herein) The <u>treatment</u> system of claim 1 further comprising a plurality of burn/wet scrubbers in fluid communication with <u>a single</u> local <u>said localized</u> wastewater treatment unit.
 - 3. (cancelled herein)

- 4. (cancelled herein)
- 5. (amended herein) The <u>treatment</u> system of claim 1 and including <u>additionally comprising</u> a central wastewater treatment facility for receiving and further treating the locally treated wastewater.
- 6. (amended herein) The <u>treatment</u> system of claim [[1]]5 further comprising a plurality of burn/wet scrubbers and a plurality of <u>localized</u> wastewater treatment units wherein each <u>said</u> burn/wet scrubbers is in fluid communication with a <u>corresponding localized</u> wastewater treatment unit, and each said <u>localized</u> wastewater treatment unit is in fluid communication with the central wastewater treatment facility.

7-14. (withdrawn)

- 15. (new) The treatment system of claim 1 wherein said ion exchange filter is selected to reduce the concentration of arsenic and germanium.
- 16. (new) The treatment system of claim 15 wherein said ion exchange filter is selected to reduce the concentration of arsenic to a concentration below 50 ppb.
- 17. (new) The treatment system of claim 15 wherein said ion exchange filter is selected to reduce the concentration of germanium to a concentration below 50 ppb.